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TLV2470, TLV2471
TLV2472, TLV2473
TLV2474, TLV2475, TLV247xA
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FAMILY OF 600µA/Ch 2.8MHz RAIL-TO-RAIL INPUT/OUTPUT HIGH-DRIVE OPERATIONAL AMPLIFIERS WITH SHUTDOWN

FEATURES

- **CMOS Rail-To-Rail Input/Output**
- **Input Bias Current: 2.5pA**
- **Low Supply Current: 600µA/Channel**
- **Ultra-Low Power Shutdown Mode:**
  $I_{DD(SHDN)}$: **350nA/ch at 3V**
  $I_{DD(SHDN)}$: **1000nA/ch at 5V**
- **Gain-Bandwidth Product: 2.8MHz**
- **High Output Drive Capability:**
  - **±10mA at 180mV**
  - **±35mA at 500mV**
- **Input Offset Voltage: 250µV (typ)**
- **Supply Voltage Range: 2.7V to 6V**
- **Ultra-Small Packaging**
  - **SOT23-5 or -6 (TLV2470/1)**
  - **MSOP-8 or -10 (TLV2472/3)**

DESCRIPTION

The TLV247x is a family of CMOS rail-to-rail input/output operational amplifiers that establishes a new performance point for supply current versus ac performance. These devices consume just 600µA/channel while offering 2.8MHz of gain-bandwidth product. Along with increased ac performance, the amplifier provides high output drive capability, solving a major shortcoming of older micropower operational amplifiers. The TLV247x can swing to within 180mV of each supply rail while driving a 10mA load. For non-RRO applications, the TLV247x can supply ±35mA at 500mV off the rail. Both the inputs and outputs swing rail-to-rail for increased dynamic range in low-voltage applications. This performance makes the TLV247x family ideal for sensor interface, portable medical equipment, and other data acquisition circuits.

FAMILY PACKAGE TABLE

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES					SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	SOIC	SOT23	TSSOP	MSOP		
TLV2470	1	8	8	6	—	—	Yes	
TLV2471	1	8	8	5	—	—	—	
TLV2472	2	8	8	—	—	8	—	Refer to the EVM Selection Guide (SLOU060)
TLV2473	2	14	14	—	—	10	Yes	
TLV2474	4	14	14	—	14	—	—	
TLV2475	4	16	16	—	16	—	Yes	

A SELECTION OF SINGLE-SUPPLY OPERATIONAL AMPLIFIER PRODUCTS[1]

DEVICE	V_{DD} (V)	V_{IO} (µV)	BW (MHz)	SLEW RATE (V/µs)	I_{DD} (per channel) (µA)	OUTPUT DRIVE	RAIL-TO-RAIL
TLV247X	2.7 – 6.0	250	2.8	1.5	600	±35mA	I/O
TLV245X	2.7 – 6.0	20	0.22	0.11	23	±10mA	I/O
TLV246X	2.7 – 6.0	150	6.4	1.6	550	±90mA	I/O
TLV277X	2.5 – 6.0	360	5.1	10.5	1000	±10mA	O

(1) All specifications measured at 5V.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

TLV2470 and TLV2471 AVAILABLE OPTIONS[1]

T_A	PACKAGED DEVICES			
	SMALL OUTLINE (D)[2]	SOT23		PLASTIC DIP (P)
		(DBV)[2]	SYMBOL	
0°C to +70°C	TLV2470CD TLV2471CD	TLV2470CDBV TLV2471CDBV	VAUC VAVC	TLV2470CP TLV2471CP
−40°C to +125°C	TLV2470ID TLV2471ID	TLV2470IDBV TLV2471IDBV	VAUI VAVI	TLV2470IP TLV2471IP
	TLV2470AID TLV2471AID	———	———	TLV2470AIP TLV2471AIP

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (for example, TLV2470CDR).

TLV2472 AND TLV2473 AVAILABLE OPTIONS[1]

T_A	PACKAGED DEVICES						
	SMALL OUTLINE (D)[2]	MSOP		MSOP		PLASTIC DIP (N)	PLASTIC DIP (P)
		(DGN)[2]	SYMBOL[3]	(DGQ)[2]	SYMBOL[3]		
0°C to +70°C	TLV2472CD TLV2473CD	TLV2472CDGN —	xxTIABU —	— TLV2473CDGQ	— xxTIABW	— TLV2473CN	TLV2472CP —
−40°C to +125°C	TLV2472ID TLV2473ID	TLV2472IDGN —	xxTIABV —	— TLV2473IDGQ	— xxTIABX	— TLV2473IN	TLV2472IP —
	TLV2472AID TLV2473AID	———	———	———	———	— TLV2473AIN	TLV2472AIP —

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (for example, TLV2472CDR).
(3) xx represents the device date code.

TLV2474 and TLV2475 AVAILABLE OPTIONS[1]

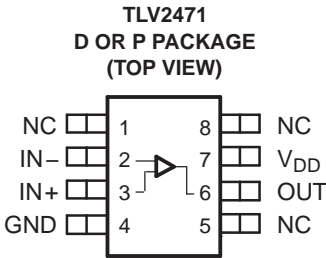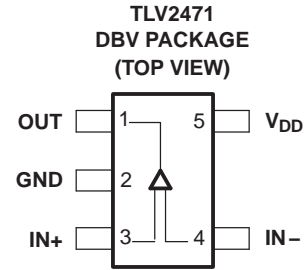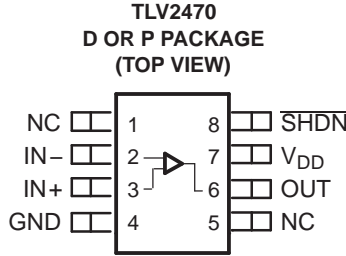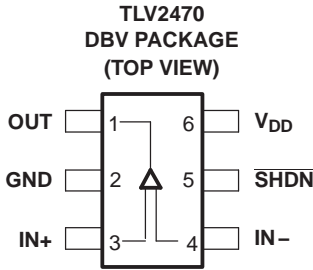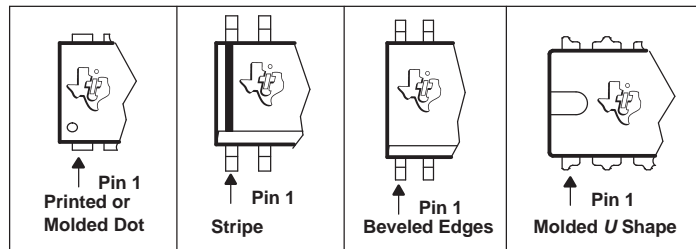| T_A	PACKAGED DEVICES		
	SMALL OUTLINE (D)[2]	PLASTIC DIP (N)	TSSOP (PWP)[2]
0°C to +70°C	TLV2474CD TLV2475CD	TLV2474CN TLV2475CN	TLV2474CPWP TLV2475CPWP
−40°C to +125°C	TLV2474ID TLV2475ID	TLV2474IN TLV2475IN	TLV2474IPWP TLV2475IPWP
	TLV2474AID TLV2475AID	TLV2474AIN TLV2475AIN	TLV2474AIPWP TLV2475AIPWP

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (for example, TLV2474CDR).

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TLV247X PACKAGE PINOUTS

TLV2470
DBV PACKAGE
(TOP VIEW)

OUT	1	6	V_{DD}
GND	2	5	$\overline{SHDN}$
IN+	3	4	IN−

TLV2470
D OR P PACKAGE
(TOP VIEW)

NC	1	8	$\overline{SHDN}$
IN−	2	7	V_{DD}
IN+	3	6	OUT
GND	4	5	NC

TLV2471
DBV PACKAGE
(TOP VIEW)

OUT	1	5	V_{DD}
GND	2		
IN+	3	4	IN−

TLV2471
D OR P PACKAGE
(TOP VIEW)

NC	1	8	NC
IN−	2	7	V_{DD}
IN+	3	6	OUT
GND	4	5	NC

TLV2472
D, DGN, OR P PACKAGE
(TOP VIEW)

1OUT	1	8	V_{DD}
1IN−	2	7	2OUT
1IN+	3	6	2IN−
GND	4	5	2IN+

TLV2473
DGQ PACKAGE
(TOP VIEW)

1OUT	1	10	V_{DD}
1IN−	2	9	2OUT
1IN+	3	8	2IN−
GND	4	7	2IN+
$\overline{1SHDN}$	5	6	$\overline{2SHDN}$

TLV2473
D OR N PACKAGE
(TOP VIEW)

1OUT	1	14	V_{DD}
1IN−	2	13	2OUT
1IN+	3	12	2IN−
GND	4	11	2IN+
NC	5	10	NC
$\overline{1SHDN}$	6	9	$\overline{2SHDN}$
NC	7	8	NC

TLV2474
D, N, OR PWP PACKAGE
(TOP VIEW)

1OUT	1	14	4OUT
1IN−	2	13	4IN−
1IN+	3	12	4IN+
V_{DD}	4	11	GND
2IN+	5	10	3IN+
2IN−	6	9	3IN−
2OUT	7	8	3OUT

TLV2475
D, N, OR PWP PACKAGE
(TOP VIEW)

1OUT	1	16	4OUT
1IN−	2	15	4IN−
1IN+	3	14	4IN+
V_{DD}	4	13	GND
2IN+	5	12	3IN+
2IN−	6	11	3IN−
2OUT	7	10	3OUT
$\overline{1/2SHDN}$	8	9	$\overline{3/4SHDN}$

NC − No internal connection

TYPICAL PIN 1 INDICATORS

| Pin 1 Printed or Molded Dot | Pin 1 Stripe | Pin 1 Beveled Edges | Pin 1 Molded *U* Shape |

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DESCRIPTION (CONTINUED)

Three members of the family (TLV2470/3/5) offer a shutdown terminal for conserving battery life in portable applications. During shutdown, the outputs are placed in a high-impedance state and the amplifier consumes only 350nA/channel. The family is fully specified at 3V and 5V across an expanded industrial temperature range (−40°C to +125°C). The singles and duals are available in the SOT23 and MSOP packages, while the quads are available in TSSOP. The TLV2470 offers an amplifier with shutdown functionality all in a SOT23-6 package, making it perfect for high-density power-sensitive circuits.

ABSOLUTE MAXIMUM RATINGS[1]

Over operating free-air temperature range, unless otherwise noted.

		UNIT
Supply voltage, V_{DD}[2]		7V
Differential input voltage, V_{ID}		$\pm V_{DD}$
Continuous total power dissipation		See Dissipation Rating table
Operating free-air temperature range, T_A	C-suffix	0°C to +70°C
	I-suffix	−40°C to +125°C
Maximum junction temperature, T_J		+150°C
Storage temperature range, T_{stg}		−65°C to +150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		+260°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq$ +25°C POWER RATING
D (8)	38.3	176	710mW
D (14)	26.9	122.3	1022mW
D (16)	25.7	114.7	1090mW
DBV (5)	55	324.1	385mW
DBV (6)	55	294.3	425mW
DGN (8)	4.7	52.7	2.37W
DGQ (10)	4.7	52.3	2.39W
N (14, 16)	32	78	1600mW
P (8)	41	104	1200mW
PWP (14)	2.07	30.7	4.07W
PWP (16)	2.07	29.7	4.21W

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply	2.7	6	V
	Split supply	±1.35	±3	
Common-mode input voltage range, V_{ICR}		0	V_{DD}	V
Operating free-air temperature, T_A	C-suffix	0	+70	°C
	I-suffix	−40	+125	
Shutdown on/off voltage level[1]	V_{IH}	2		V
	V_{IL}		0.8	

(1) Relative to GND.

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ELECTRICAL CHARACTERISTICS

At specified free-air temperature, V_{DD} = 3V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A[1]	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_S = 50\Omega$	TLV247x	+25°C		250	2200	µV
				Full range			2400	
			TLV247xA	+25°C		250	1600	
				Full range			1800	
α_{VIO}	Temperature coefficient of input offset voltage					0.4		µV/°C
I_{IO}	Input offset current			25°C		1.5	50	pA
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
I_{IB}	Input bias current			+25°C		2	50	
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
V_{OH}	High-level output voltage	$V_{IC} = V_{DD}/2$	$I_{OH} = -2.5mA$	+25°C	2.85	2.94		V
				Full range	2.8			
			$I_{OH} = -10mA$	+25°C	2.6	2.74		
				Full range	2.5			
V_{OL}	Low-level output voltage	$V_{IC} = V_{DD}/2$	$I_{OL} = 2.5mA$	+25°C		0.07	0.15	V
				Full range			0.2	
			$I_{OL} = 10mA$	+25°C		0.2	0.35	
				Full range			0.5	
I_{OS}	Short-circuit output current	Sourcing		+25°C	30			mA
				Full range	20			
		Sinking		+25°C	30			
				Full range	20			
I_O	Output current	$V_O = 0.5V$ from rail		+25°C		±22		mA
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)} = 1V$, $R_L = 10k\Omega$		+25°C	90	116		dB
				Full range	88			
$r_{i(d)}$	Differential input resistance			+25°C		10^{12}		Ω
C_{IC}	Common-mode input capacitance	$f = 10kHz$		+25°C		19.3		pF
z_o	Closed-loop output impedance	$f = 10kHz$, $A_V = 10$		+25°C		2		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = 0V$ to 3V, $R_S = 50\Omega$		+25°C	61	78		dB
			TLV247xC	Full range	59			
			TLV247xI	Full range	58			

(1)   Full range is 0°C to +70°C for C-suffix and −40°C to +125°C for I-suffix. If not specified, full range is −40°C to +125°C.

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ELECTRICAL CHARACTERISTICS (continued)

At specified free-air temperature, $V_{DD} = 3V$, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A[1]	MIN	TYP	MAX	UNIT
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7V$ to $6V$, $V_{IC} = V_{DD}/2$, No load		+25°C	74	90		dB
				Full range	66			
		$V_{DD} = 3V$ to $5V$, $V_{IC} = V_{DD}/2$, No load		+25°C	77	92		
				Full range	68			
I_{DD}	Supply current (per channel)	$V_O = 1.5V$, No load		+25°C		550	750	μA
				Full range			800	
$I_{DD(SHDN)}$	Supply current in shutdown mode (TLV2470, TLV2473, TLV2475) (per channel)	$\overline{SHDN} = 0V$		+25°C		350	1500	nA
			TLV247xC	Full range			2000	
			TLV247xI	Full range			4000	

(1) Full range is 0°C to +70°C for C-suffix and −40°C to +125°C for I-suffix. If not specified, full range is −40°C to +125°C.

OPERATING CHARACTERISTICS

At specified free-air temperature, $V_{DD} = 3V$, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A[1]	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_{O(PP)} = 0.8V$, $C_L = 150pF$, $R_L = 10k\Omega$		+25°C	1.1	1.4		V/μs
				Full range	0.6			
V_n	Equivalent input noise voltage	f = 100Hz		+25°C		28		nV/√Hz
		f = 1kHz		+25°C		15		
I_n	Equivalent input noise current	f = 1kHz		+25°C		0.405		pA/√Hz
THD+N	Total harmonic distortion plus noise	$V_{O(PP)} = 2V$, $R_L = 10k\Omega$, f = 1kHz	$A_V = 1$	+25°C		0.02%		
			$A_V = 10$			0.1%		
			$A_V = 100$			0.5%		
$t_{(on)}$	Amplifier turn-on time	$R_L = OPEN$[2]		+25°C		5		μs
$t_{(off)}$	Amplifier turn-off time			+25°C		250		ns
	Gain-bandwidth product	f = 10kHz, $R_L = 600\Omega$		+25°C		2.8		MHz
t_s	Settling time	$V_{(STEP)PP} = 2V$, $A_V = −1$, $C_L = 10pF$, $R_L = 10k\Omega$	0.1%	+25°C		1.5		μs
			0.01%			3.9		
		$V_{(STEP)PP} = 2V$, $A_V = −1$, $C_L = 56pF$, $R_L = 10k\Omega$	0.1%			1.6		
			0.01%			4		
Φ_m	Phase margin	$R_L = 10k\Omega$, $C_L = 1000pF$		+25°C		61		°
	Gain margin	$R_L = 10k\Omega$, $C_L = 1000pF$		+25°C		15		dB

(1) Full range is 0°C to +70°C for C-suffix and −40°C to +125°C for I-suffix. If not specified, full range is −40°C to +125°C.
(2) Disable and enable time are defined as the interval between application of logic signal to $\overline{SHDN}$ and the point at which the supply current has reached half its final value.

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ELECTRICAL CHARACTERISTICS

At specified free-air temperature, V_{DD} = 5V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A[(1)]	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_S = 50\Omega$	TLV247x	+25°C		250	2200	µV
				Full range			2400	
			TLV247xA	+25°C		250	1600	
				Full range			2000	
α_{VIO}	Temperature coefficient of input offset voltage					0.4		µV/°C
I_{IO}	Input offset current			+25°C		1.7	50	pA
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
I_{IB}	Input bias current			+25°C		2.5	50	
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
V_{OH}	High-level output voltage	$V_{IC} = V_{DD}/2$	$I_{OH} = -2.5mA$	+25°C	4.85	4.96		V
				Full range	4.8			
			$I_{OH} = -10mA$	+25°C	4.72	4.82		
				Full range	4.65			
V_{OL}	Low-level output voltage	$V_{IC} = V_{DD}/2$	$I_{OL} = 2.5mA$	+25°C		0.07	0.15	V
				Full range			0.2	
			$I_{OL} = 10mA$	+25°C		0.178	0.28	
				Full range			0.35	
I_{OS}	Short-circuit output current	Sourcing		+25°C	110			mA
				Full range	60			
		Sinking		+25°C	90			
				Full range	60			
I_O	Output current	$V_O = 0.5V$ from rail		+25°C		±35		mA
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)} = 3V$, $R_L = 10k\Omega$		+25°C	92	120		dB
				Full range	91			
$r_{i(d)}$	Differential input resistance			+25°C		10^{12}		Ω
C_{IC}	Common-mode input capacitance	f = 10kHz		+25°C		18.9		pF
z_o	Closed-loop output impedance	f = 10kHz, $A_V = 10$		+25°C		1.8		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = 0V$ to 5V, $R_S = 50\Omega$		+25°C	64	84		dB
			TLV247xC	Full range	63			
			TLV247xI	Full range	58			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7V$ to 6V, $V_{IC} = V_{DD}/2$, No load		+25°C	74	90		dB
				Full range	66			
		$V_{DD} = 3V$ to 5V, $V_{IC} = V_{DD}/2$, No load		+25°C	77	92		
				Full range	66			
I_{DD}	Supply current (per channel)	$V_O = 2.5V$, No load		+25°C		600	900	µA
				Full range			1000	

(1) Full range is 0°C to +70°C for C-suffix and −40°C to +125°C for I-suffix. If not specified, full range is −40°C to +125°C.

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ELECTRICAL CHARACTERISTICS (continued)

At specified free-air temperature, V_{DD} = 5V, unless otherwise noted.

PARAMETER		TEST CONDITIONS	T_A[1]	MIN	TYP	MAX	UNIT
$I_{DD(SHDN)}$	Supply current in shutdown mode (TLV2470, TLV2473, TLV2475) (per channel)	$\overline{SHDN}$ = 0V	+25°C		1000	2500	nA
			TLV247xC Full range			3000	
			TLV247xI Full range			6000	nA

(1) Full range is 0°C to +70°C for C-suffix and −40°C to +125°C for I-suffix. If not specified, full range is −40°C to +125°C.

OPERATING CHARACTERISTICS

At specified free-air temperature, V_{DD} = 5V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A[1]	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_{O(PP)}$ = 2V, C_L = 150pF, R_L= 10kΩ		+25°C	1.1	1.5		V/µs
				Full range	0.7			
V_n	Equivalent input noise voltage	f = 100Hz		+25°C		28		nV/√Hz
		f = 1kHz		+25°C		15		
I_n	Equivalent input noise current	f = 1kHz		+25°C		0.39		pA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 4V, R_L= 10kΩ, f = 1kHz	A_V = 1	+25°C		0.01%		
			A_V = 10			0.05%		
			A_V = 100			0.3%		
$t_{(on)}$	Amplifier turn-on time	R_L= OPEN[2]		+25°C		5		µs
$t_{(off)}$	Amplifier turn-off time			+25°C		250		ns
	Gain-bandwidth product	f = 10kHz, R_L = 600Ω		+25°C		2.8		MHz
t_s	Settling time	$V_{(STEP)PP}$ = 2V, A_V = −1, C_L = 10pF, R_L = 10kΩ	0.1%	+25°C		1.8		µs
			0.01%			3.3		
		$V_{(STEP)PP}$ = 2V, A_V = −1, C_L = 56pF, R_L = 10kΩ	0.1%			1.7		
			0.01%			3		
Φ_m	Phase margin	R_L = 10kΩ, C_L = 1000pF		+25°C		68		°C
	Gain margin	R_L = 10kΩ, C_L = 1000pF		+25°C		23		dB

(1) Full range is 0°C to +70°C for C suffix and −40°C to +125°C for I suffix. If not specified, full range is −40°C to +125°C.
(2) Disable and enable time are defined as the interval between application of logic signal to $\overline{SHDN}$ and the point at which the supply current has reached half its final value.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	Figure 1, Figure 2
I_{IB}	Input bias current	vs Free-air temperature	Figure 3, Figure 4
I_{IO}	Input offset current		
V_{OH}	High-level output voltage	vs High-level output current	Figure 5, Figure 7
V_{OL}	Low-level output voltage	vs Low-level output current	Figure 6, Figure 8
Z_o	Output impedance	vs Frequency	Figure 9
I_{DD}	Supply current	vs Supply voltage	Figure 10
PSRR	Power-supply rejection ratio	vs Frequency	Figure 11
CMRR	Common-mode rejection ratio	vs Frequency	Figure 12
V_n	Equivalent input noise voltage	vs Frequency	Figure 13
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	Figure 14, Figure 15
A_{VD}	Differential voltage gain and phase	vs Frequency	Figure 16, Figure 17
Φ_m	Phase margin	vs Load capacitance	Figure 18, Figure 19
	Gain margin	vs Load capacitance	Figure 20, Figure 21
	Gain-bandwidth product	vs Supply voltage	Figure 22
SR	Slew rate	vs Supply voltage	Figure 23
		vs Free-air temperature	Figure 24, Figure 25
	Crosstalk	vs Frequency	Figure 26
THD+N	Total harmonic distortion + noise	vs Frequency	Figure 27, Figure 28
V_O	Large and small signal follower	vs Time	Figure 29–Figure 32
	Shutdown pulse response	vs Time	Figure 33, Figure 34
	Shutdown forward and reverse isolation	vs Frequency	Figure 35, Figure 36
$I_{DD(SHDN)}$	Shutdown supply current	vs Supply voltage	Figure 37
$I_{DD(SHDN)}$	Shutdown supply current	vs Free-air temperature	Figure 38
$I_{DD(SHDN)}$	Shutdown pulse current	vs Time	Figure 39, Figure 40

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TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT VOLTAGE

$V_{DD} = 3V$
$T_A = +25°C$

Figure 1.

INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT VOLTAGE

$V_{DD} = 5V$
$T_A = +25°C$

Figure 2.

INPUT BIAS AND INPUT OFFSET
CURRENTS
vs
FREE-AIR TEMPERATURE

$V_{DD} = 3V$

I_{IB}

I_{IO}

Figure 3.

INPUT BIAS AND INPUT OFFSET
CURRENTS
vs
FREE-AIR TEMPERATURE

$V_{DD} = 5V$

I_{IB}

I_{IO}

Figure 4.

HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

$V_{DD} = 3V$

$T_A = +125°C$
$T_A = +85°C$
$T_A = +25°C$
$T_A = -40°C$

Figure 5.

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

$V_{DD} = 3V$
$T_A = +125°C$
$T_A = +85°C$
$T_A = +25°C$
$T_A = -40°C$

Figure 6.

HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

$V_{DD} = 5V$

$T_A = +125°C$
$T_A = +85°C$
$T_A = +25°C$
$T_A = -40°C$

Figure 7.

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

$T_A = +125°C$
$T_A = +85°C$
$T_A = +25°C$
$T_A = -40°C$

$V_{DD} = 5V$

Figure 8.

OUTPUT IMPEDANCE
vs
FREQUENCY

$V_{DD} = 3V, 5V$
$T_A = +25°C$

$A_V = 100$

$A_V = 10$

$A_V = 1$

Figure 9.

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TYPICAL CHARACTERISTICS (continued)

**SUPPLY CURRENT
vs
SUPPLY VOLTAGE**

Figure 10.

**POWER-SUPPLY REJECTION
RATIO
vs
FREQUENCY**

Figure 11.

**COMMON-MODE REJECTION RATIO
vs
FREQUENCY**

Figure 12.

**EQUIVALENT NOISE VOLTAGE
vs
FREQUENCY**

Figure 13.

**MAXIMUM PEAK-TO-PEAK
OUTPUT VOLTAGE
vs
FREQUENCY**

Figure 14.

**MAXIMUM PEAK-TO-PEAK
OUTPUT VOLTAGE
vs
FREQUENCY**

Figure 15.

**DIFFERENTIAL VOLTAGE GAIN
AND PHASE
vs
FREQUENCY**

Figure 16.

**DIFFERENTIAL VOLTAGE GAIN
AND PHASE
vs
FREQUENCY**

Figure 17.

TLV2470, TLV2471
TLV2472, TLV2473
TLV2474, TLV2475, TLV247xA

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TYPICAL CHARACTERISTICS (continued)

PHASE MARGIN
vs
LOAD CAPACITANCE

Figure 18.

PHASE MARGIN
vs
LOAD CAPACITANCE

Figure 19.

GAIN MARGIN
vs
LOAD CAPACITANCE

Figure 20.

GAIN MARGIN
vs
LOAD CAPACITANCE

Figure 21.

GAIN-BANDWIDTH PRODUCT
vs
SUPPLY VOLTAGE

Figure 22.

SLEW RATE
vs
SUPPLY VOLTAGE

Figure 23.

SLEW RATE
vs
FREE-AIR TEMPERATURE

Figure 24.

SLEW RATE
vs
FREE-AIR TEMPERATURE

Figure 25.

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TLV2470, TLV2471
TLV2472, TLV2473
TLV2474, TLV2475, TLV247xA

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TYPICAL CHARACTERISTICS (continued)

**CROSSTALK
vs
FREQUENCY**

Figure 26.

**TOTAL HARMONIC
DISTORTION PLUS NOISE
vs
FREQUENCY**

Figure 27.

**TOTAL HARMONIC
DISTORTION PLUS NOISE
vs
FREQUENCY**

Figure 28.

**LARGE-SIGNAL FOLLOWER
PULSE RESPONSE
vs
TIME**

Figure 29.

**LARGE-SIGNAL FOLLOWER
PULSE RESPONSE
vs
TIME**

Figure 30.

**SMALL-SIGNAL FOLLOWER
PULSE RESPONSE
vs
TIME**

Figure 31.

**SMALL-SIGNAL FOLLOWER
PULSE RESPONSE
vs
TIME**

Figure 32.

**SHUTDOWN (ON AND OFF)
PULSE RESPONSE
vs
TIME**

Figure 33.

**SHUTDOWN (ON AND OFF)
PULSE RESPONSE
vs
TIME**

Figure 34.

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TLV2470, TLV2471
TLV2472, TLV2473
TLV2474, TLV2475, TLV247xA

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TYPICAL CHARACTERISTICS (continued)

**SHUTDOWN FORWARD
ISOLATION
vs
FREQUENCY**

Figure 35.

**SHUTDOWN REVERSE ISOLATION
vs
FREQUENCY**

Figure 36.

**SHUTDOWN SUPPLY CURRENT
vs
SUPPLY VOLTAGE**

Figure 37.

**SHUTDOWN SUPPLY CURRENT
vs
FREE-AIR TEMPERATURE**

Figure 38.

**SHUTDOWN PULSE CURRENT
vs
TIME**

Figure 39.

**SHUTDOWN PULSE CURRENT
vs
TIME**

Figure 40.

PARAMETER MEASUREMENT INFORMATION
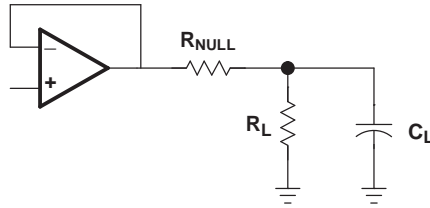
Figure 41.

APPLICATION INFORMATION

DRIVING A CAPACITIVE LOAD

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device phase margin leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10pF, it is recommended that a resistor (R_{NULL}) be placed in series with the output of the amplifier, as shown in Figure 42. A minimum value of 20Ω should work well for most applications.
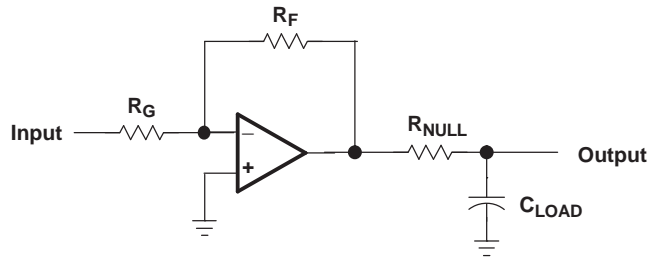
Figure 42. Driving a Capacitive Load

OFFSET VOLTAGE

The output offset voltage (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:
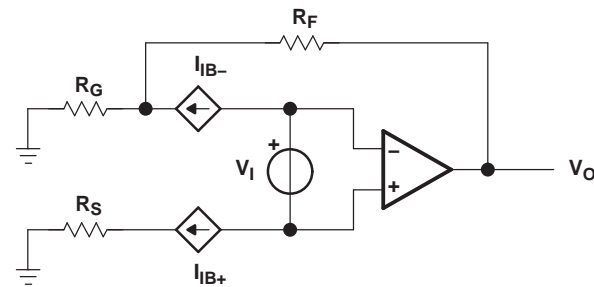
$$V_{OO} = V_{IO}\left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB+}\, R_S \left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB-}\, R_F$$

Figure 43. Output Offset Voltage Model

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APPLICATION INFORMATION (continued)

GENERAL CONFIGURATIONS

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 44).

$$f_{-3dB} = \frac{1}{2\pi R1 C1}$$

$$\frac{V_O}{V_I} = \left(1 + \frac{R_F}{R_G}\right)\left(\frac{1}{1 + sR1C1}\right)$$
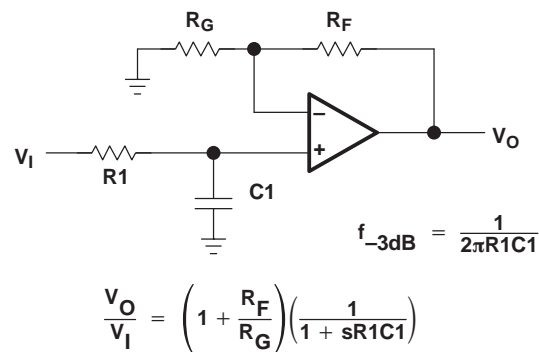
Figure 44. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is eight to ten times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

R1 = R2 = R
C1 = C2 = C
Q = Peaking Factor
(Butterworth Q = 0.707)

$$f_{-3dB} = \frac{1}{2\pi RC}$$

$$R_G = \frac{R_F}{\left(2 - \frac{1}{Q}\right)}$$
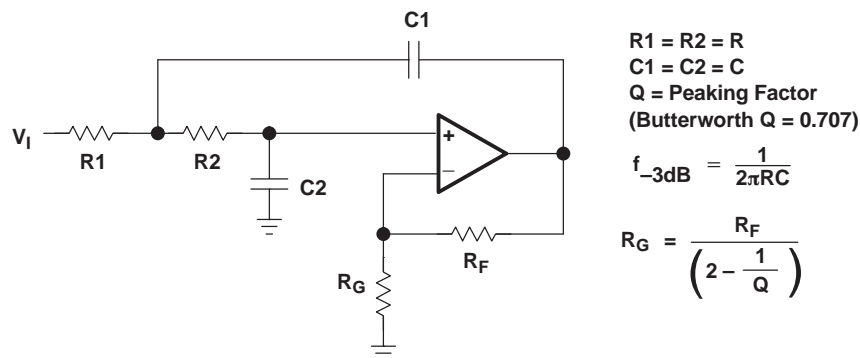
Figure 45. 2-Pole Low-Pass Sallen-Key Filter

SHUTDOWN FUNCTION

Three members of the TLV247x family (TLV2470/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 350nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to $V_{DD}/2$. Therefore, when operating the device with split supply voltages (e.g., ±2.5V), the shutdown terminal needs to be pulled to V_{DD}− (not GND) to disable the operational amplifier.

The amplifier output with a shutdown pulse is shown in Figure 33 and Figure 34. The amplifier is powered with a single 5V supply and configured as a noninverting configuration with a gain of 5. The amplifier turn-on and turn-off times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad versions are listed in the data tables.

APPLICATION INFORMATION (continued)

Figure 35 and Figure 36 show the amplifier forward and reverse isolation in shutdown. The operational amplifier is powered by $\pm1.35V$ supplies and configured as a voltage follower ($A_V= 1$). The isolation performance is plotted across frequency using $0.1V_{PP}$, $1.5V_{PP}$, and $2.5V_{PP}$ input signals. During normal operation, the amplifier would not be able to handle a $2.5V_{PP}$ input signal with a supply voltage of $\pm1.35V$ since it exceeds the common-mode input voltage range (V_{ICR}). However, this curve illustrates that the amplifier remains in shutdown even under a worst case scenario.

CIRCUIT LAYOUT CONSIDERATIONS

To achieve the levels of high performance of the TLV247x, follow proper printed circuit board (PCB) design techniques. A general set of guidelines is given below:

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8μF tantalum capacitor in parallel with a 0.1μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high-performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

GENERAL PowerPAD™ DESIGN CONSIDERATIONS

The TLV247x is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted (see Figure 46a and Figure 46b). This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package (see Figure 46c). Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad must be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

Soldering the PowerPAD to the PCB is always recommended, even with applications that have low power dissipation. It provides the necessary mechanical and thermal connection between the lead frame die pad and the PCB.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with previously awkward mechanical methods of heatsinking.
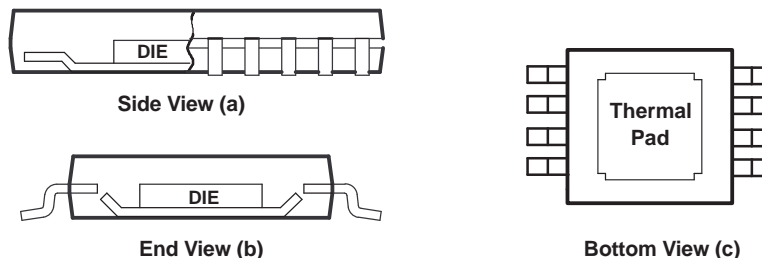
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APPLICATION INFORMATION (continued)

Figure 46. Views of Thermally Enhanced DGN Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

1. The thermal pad must be connected to the most negative supply voltage on the device (GND pin).

2. Prepare the PCB with a top side etch pattern as illustrated in the thermal land pattern mechanical drawing at the end of this document. There should be etch for the leads as well as etch for the thermal pad.

3. Place holes in the area of the thermal pad as illustrated in the land pattern mechanical drawing at the end of this document. These holes should be 13mils (0.013 inches or 0.3302mm) in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.

4. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the TLV247x IC. These additional vias may be larger than the 13mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.

5. Connect all holes to the internal ground plane that is at the same voltage potential as the device GND pin.

6. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the TLV247x PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.

7. The top-side solder mask should leave the terminals of the package and the thermal pad area with its holes exposed. The bottom-side solder mask should cover the holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.

8. Apply solder paste to the exposed thermal pad area and all of the IC terminals.

9. With these preparatory steps in place, the TLV247x IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

For a given θ_{JA}, the maximum power dissipation is shown in Figure 47 and is calculated by Equation 1:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

(1)

Where:

- P_D = Maximum power dissipation of TLV247x IC (watts)
- T_{MAX} = Absolute maximum junction temperature (+150°C)
- T_A = Free-ambient air temperature (°C)
- $\theta_{JA} = \theta_{JC} + \theta_{CA}$
  - θ_{JC} = Thermal coefficient from junction to case
  - θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

APPLICATION INFORMATION (continued)

MAXIMUM POWER DISSIPATION
vs
FREE-AIR TEMPERATURE
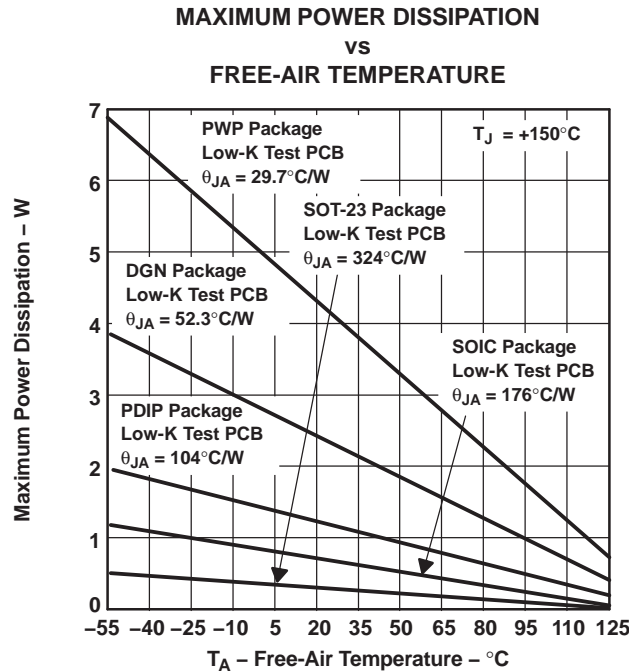
Results are obtained with no air flow and using JEDEC Standard Low-K test PCB.

Figure 47. Maximum Power Dissipation vs Free-Air Temperature

The next consideration is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents. Figure 48 to Figure 53 show this effect, along with the quiescent heat, with an ambient air temperature of +70°C and +125°C. When using V_{DD} = 3V, there is generally not a heat problem with an ambient air temperature of +70°C. But, when using V_{DD} = 5V, the package is severely limited in the amount of heat it can dissipate. The other key factor when looking at these graphs is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat dissipation. But the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual or quad amplifier packages, the sum of the RMS output currents and voltages should be used to choose the proper package.

APPLICATION INFORMATION (continued)

TLV2470, TLV2471[1]
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

Figure 48.

TLV2470, TLV2471[1]
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

Figure 49.

TLV2472, TLV2473[1]
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

Figure 50.

TLV2472, TLV2473[1]
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

Figure 51.

Note: (1) A - SOT23 (5); B - SOT23 (6); C - SOIC (8); D - SOIC (14); E - SOIC (16); F - MSOP PP (8); G - PDIP (8); H - PDIP (14): I - PDIP (16); J - TSSOP PP (14/16)

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APPLICATION INFORMATION (continued)

TLV2474, TLV2475[1]
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

TLV2474, TLV2475[1]
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

Figure 52.

Figure 53.

NOTE: (1) A - SOT23 (5); B - SOT23 (6); C - SOIC (8); D - SOIC (14); E - SOIC (16); F - MSOP PP (8); G - PDIP (8); H - PDIP (14): I - PDIP (16); J - TSSOP PP (14/16)

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APPLICATION INFORMATION (continued)

MACROMODEL INFORMATION

Macromodel information provided was derived using Microsim PARTS™, the model generation software used with Microsim PSpice®. The Boyle macromodel and subcircuit in Figure 54 are generated using the TLV247x typical electrical and operating characteristics at T_A = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

```
* TLV247x operational amplifier "macromodel" subcircuit
* created using Parts release 8.0 on 4/27/99 at 14:31
* Parts is a MicroSim product.
*
* connections:   non−inverting input
*                | inverting input
*                | | positive power supply
*                | | | negative power supply
*                | | | | output
*                | | | | |
.subckt  TLV247x 1 2 3 4 5
*
        c1      11      12      1.1094E−12
        c2      6       7       5.5000E−12
        css     10      99      556.53E−15
        dc      5       53      dy
        de      54      5       dy
        dlp     90      91      dx
        dln     92      90      dx
        dp      4       3       dx
        egnd    99      0       poly(2) (3,0) (4,0) 0 .5 .5
        fb      7       99      poly(5) vb vc ve vlp vln 0
+ 39.614E6 −1E3 1E3 40E6 −40E6
        ga      6       0       11      12      79.828E−6
        gcm     0       6       10      99      32.483E−9

        iss     10      4       dc      10.714E−6
        hlim    90      0       vlim 1K
        ioff    0       6       dc      75E−9
        j1      11      2       10 jx1
        j2      12      1       10 jx2
        r2      6       9       100.00E3
        rd1     3       11      12.527E3
        rd2     3       12      12.527E3
        ro1     8       5       10
        ro2     7       99      10
        rp      3       4       3.8023E3
        rss     10      99      18.667E6
        vb      9       0       dc 0
        vc      3       53      dc .842
        ve      54      4       dc .842
        vlim    7       8       dc 0
        vlp     91      0       dc 110
        vln     0       92      dc 110
.model  dx      D(Is=800.00E−18)
.model  dy      D(Is=800.00E−18 Rs=1m Cjo=10p)
.model  jx1     NJF(Is=1.0825E−12 Beta=594.78E−06 + Vto=−1)
.model  jx2     NJF(Is=1.0825E−12 Beta=594.78E−06 + Vto=−1)
.ends
*$
```

G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers, "IEEE Journal of Solid-State Circuits, SC-9, 353 (1974).

Figure 54. Boyle Macromodel and Subcircuit

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2470AID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470AI	Samples
TLV2470AIP	LIFEBUY	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2470AI	
TLV2470CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2470C	Samples
TLV2470CDBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	VAUC	Samples
TLV2470CDBVT	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	VAUC	Samples
TLV2470CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2470C	Samples
TLV2470CP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLV2470C	Samples
TLV2470ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470I	Samples
TLV2470IDBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAUI	Samples
TLV2470IDBVT	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAUI	Samples
TLV2470IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470I	Samples
TLV2471AID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471AI	Samples
TLV2471AIDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471AI	Samples
TLV2471AIP	LIFEBUY	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2471AI	
TLV2471CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2471C	Samples
TLV2471CDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	VAVC	Samples
TLV2471CDBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	VAVC	Samples
TLV2471CDBVTG4	ACTIVE	SOT-23	DBV	5	250	TBD	Call TI	Call TI	0 to 70		Samples
TLV2471CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2471C	Samples
TLV2471CP	LIFEBUY	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLV2471C	
TLV2471ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2471IDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAVI	Samples
TLV2471IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	TBD	Call TI	Call TI	-40 to 125		Samples
TLV2471IDBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAVI	Samples
TLV2471IDBVTG4	ACTIVE	SOT-23	DBV	5	250	TBD	Call TI	Call TI	-40 to 125		Samples
TLV2471IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471I	Samples
TLV2471IP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2471I	Samples
TLV2472AID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472AI	Samples
TLV2472AIDG4	ACTIVE	SOIC	D	8	75	TBD	Call TI	Call TI	-40 to 125		Samples
TLV2472AIDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472AI	Samples
TLV2472AIP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2472AI	Samples
TLV2472CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2472C	Samples
TLV2472CDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABU	Samples
TLV2472CDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABU	Samples
TLV2472CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2472C	Samples
TLV2472CP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLV2472CP	Samples
TLV2472ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472I	Samples
TLV2472IDGN	ACTIVE	HVSSOP	DGN	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABV	Samples
TLV2472IDGNG4	ACTIVE	HVSSOP	DGN	8	80	TBD	Call TI	Call TI	-40 to 125		Samples
TLV2472IDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABV	Samples
TLV2472IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472I	Samples
TLV2472IP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2472IP	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2473AIDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2473AI	Samples
TLV2473AIN	LIFEBUY	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2473AIN	
TLV2473CD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2473C	Samples
TLV2473CDGQR	ACTIVE	HVSSOP	DGQ	10	2500	RoHS & Green	NIPDAU | NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ABW	Samples
TLV2473CDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2473C	Samples
TLV2473IDGQR	ACTIVE	HVSSOP	DGQ	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABX	Samples
TLV2473IN	LIFEBUY	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2473IN	
TLV2474AID	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2474AI	Samples
TLV2474AIPWP	ACTIVE	HTSSOP	PWP	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474AI	Samples
TLV2474AIPWPR	ACTIVE	HTSSOP	PWP	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474AI	Samples
TLV2474AIPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474CD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2474C	Samples
TLV2474CDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2474C	Samples
TLV2474CN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLV2474C	Samples
TLV2474CPWP	ACTIVE	HTSSOP	PWP	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	2474C	Samples
TLV2474CPWPR	ACTIVE	HTSSOP	PWP	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	2474C	Samples
TLV2474ID	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474I	Samples
TLV2474IDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474I	Samples
TLV2474IN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2474I	Samples
TLV2474IPWP	ACTIVE	HTSSOP	PWP	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2474IPWPR	ACTIVE	HTSSOP	PWP	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474I	Samples
TLV2475AIDR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2475AI	Samples
TLV2475AIPWP	ACTIVE	HTSSOP	PWP	16	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475AI	Samples
TLV2475AIPWPR	ACTIVE	HTSSOP	PWP	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475AI	Samples
TLV2475CDR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2475C	Samples
TLV2475CN	LIFEBUY	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TLV2475C	
TLV2475CPWPR	ACTIVE	HTSSOP	PWP	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	2475C	Samples
TLV2475IPWPR	ACTIVE	HTSSOP	PWP	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TLV2471, TLV2471A, TLV2472, TLV2472A, TLV2474, TLV2474A :

● Automotive : TLV2471-Q1, TLV2471A-Q1, TLV2472-Q1, TLV2472A-Q1, TLV2474-Q1, TLV2474A-Q1

NOTE: Qualified Version Definitions:

  ● Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
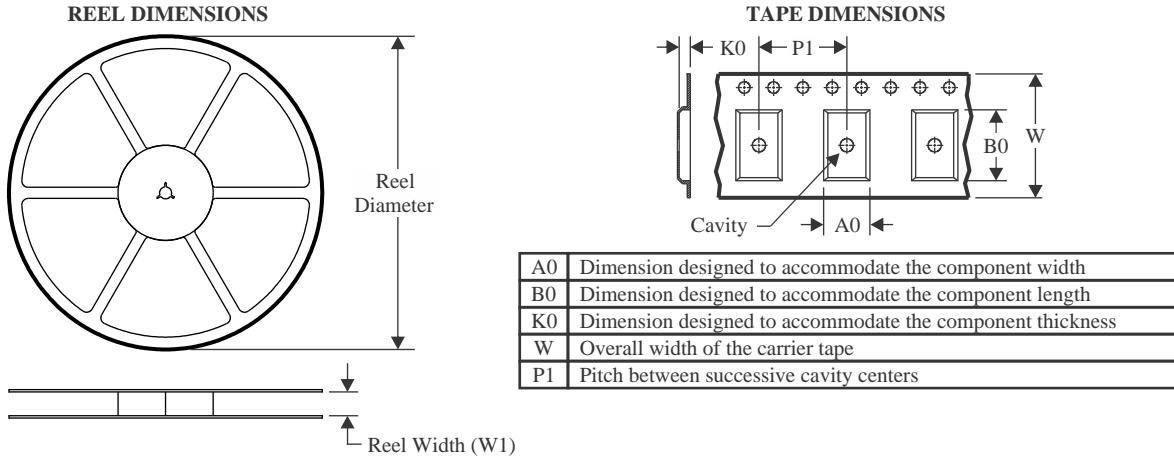
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
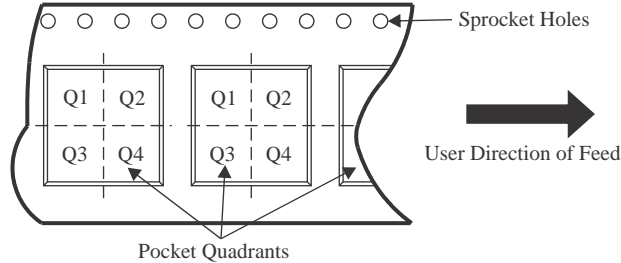
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2470CDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470CDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2470IDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470IDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2471AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2471CDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471CDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2471IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2472AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2472CDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2472CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2472IDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2472IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2473AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2473CDGQR	HVSSOP	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2473CDGQR	HVSSOP	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2473CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2473IDGQR	HVSSOP	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2474AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2474AIPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2474AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2474CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2474CPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2474IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2474IPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2475AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2475AIPWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2475CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2475CPWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2475IPWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2470CDBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TLV2470CDBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TLV2470CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2470IDBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TLV2470IDBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TLV2470IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2471AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2471CDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2471CDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2471CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2471IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2471IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2471IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2472AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2472CDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLV2472CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2472IDGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TLV2472IDR	SOIC	D	8	2500	340.5	338.1	20.6

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2473AIDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2473CDGQR	HVSSOP	DGQ	10	2500	364.0	364.0	27.0
TLV2473CDGQR	HVSSOP	DGQ	10	2500	358.0	335.0	35.0
TLV2473CDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2473IDGQR	HVSSOP	DGQ	10	2500	358.0	335.0	35.0
TLV2474AIDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2474AIPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0
TLV2474AIPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TLV2474CDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2474CPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0
TLV2474IDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2474IPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0
TLV2475AIDR	SOIC	D	16	2500	350.0	350.0	43.0
TLV2475AIPWPR	HTSSOP	PWP	16	2000	350.0	350.0	43.0
TLV2475CDR	SOIC	D	16	2500	350.0	350.0	43.0
TLV2475CPWPR	HTSSOP	PWP	16	2000	350.0	350.0	43.0
TLV2475IPWPR	HTSSOP	PWP	16	2000	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

TUBE

T - Tube height

L - Tube length

W - Tube width

B - Alignment groove width
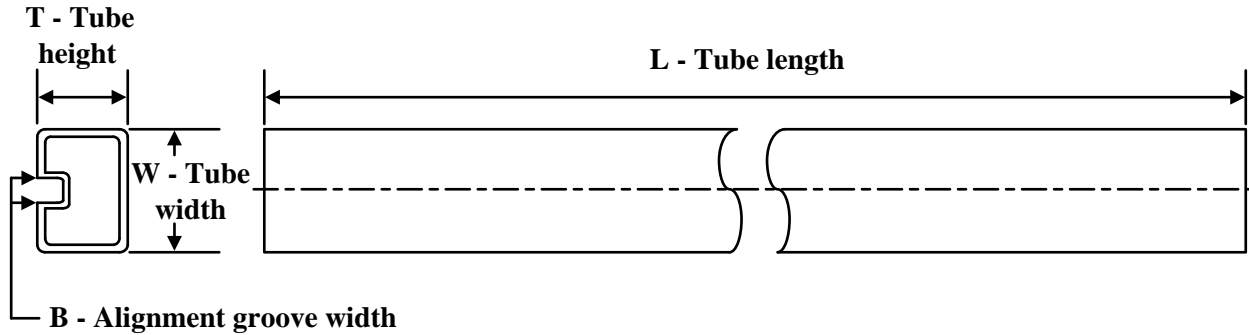
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLV2470AID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2470AID	D	SOIC	8	75	507	8	3940	4.32
TLV2470AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2470CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2470CD	D	SOIC	8	75	507	8	3940	4.32
TLV2470CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2470ID	D	SOIC	8	75	507	8	3940	4.32
TLV2470ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2471AID	D	SOIC	8	75	507	8	3940	4.32
TLV2471AID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2471AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2471CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2471CD	D	SOIC	8	75	507	8	3940	4.32
TLV2471CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2471ID	D	SOIC	8	75	507	8	3940	4.32
TLV2471ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2471IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2472AID	D	SOIC	8	75	507	8	3940	4.32
TLV2472AID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2472AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2472CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2472CD	D	SOIC	8	75	507	8	3940	4.32
TLV2472CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2472ID	D	SOIC	8	75	507	8	3940	4.32
TLV2472ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2472IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2473AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2473CD	D	SOIC	14	50	505.46	6.76	3810	4
TLV2473IN	N	PDIP	14	25	506	13.97	11230	4.32

PACKAGE MATERIALS INFORMATION

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLV2474AID	D	SOIC	14	50	505.46	6.76	3810	4
TLV2474AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2474AIPWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5
TLV2474CD	D	SOIC	14	50	505.46	6.76	3810	4
TLV2474CN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2474CPWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5
TLV2474ID	D	SOIC	14	50	505.46	6.76	3810	4
TLV2474IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2474IPWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5
TLV2475AIPWP	PWP	HTSSOP	16	90	530	10.2	3600	3.5
TLV2475CN	N	PDIP	16	25	506	13.97	11230	4.32

ALTERNATIVE PACKAGE SINGULATION VIEW

4214840/D   09/2023
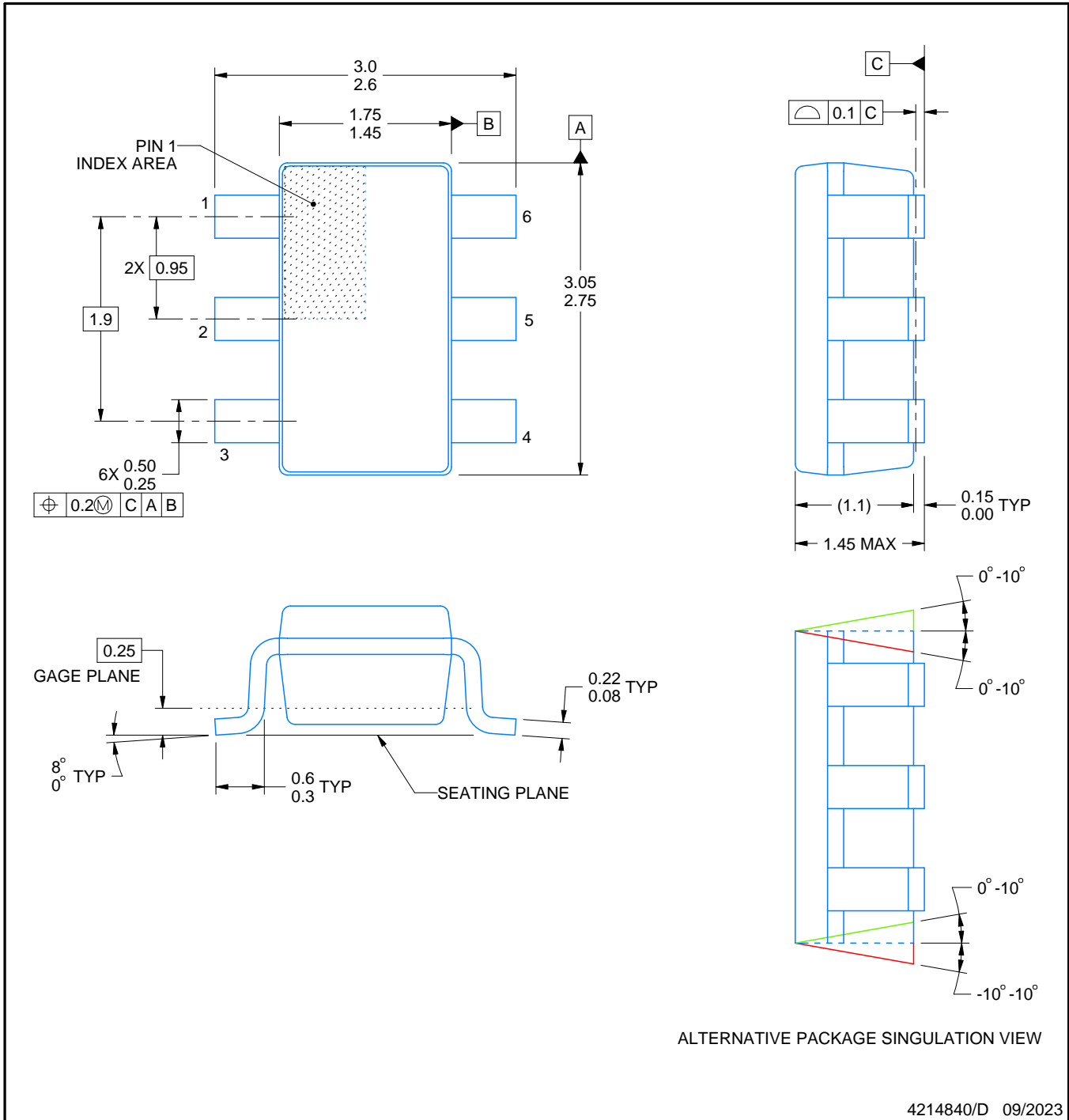
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.

6X (1.1)

PKG ℄

1

6X (0.6)

6

2X (0.95)

2

SYMM ℄

5

(R0.05) TYP

3

4

(2.6)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK OPENING

METAL

EXPOSED METAL

0.07 MAX ARROUND

NON SOLDER MASK DEFINED
(PREFERRED)

METAL UNDER SOLDER MASK

SOLDER MASK OPENING

EXPOSED METAL

0.07 MIN ARROUND
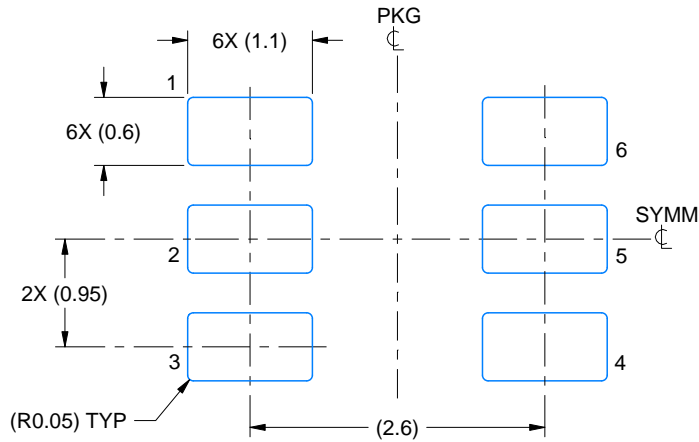
SOLDER MASK DEFINED
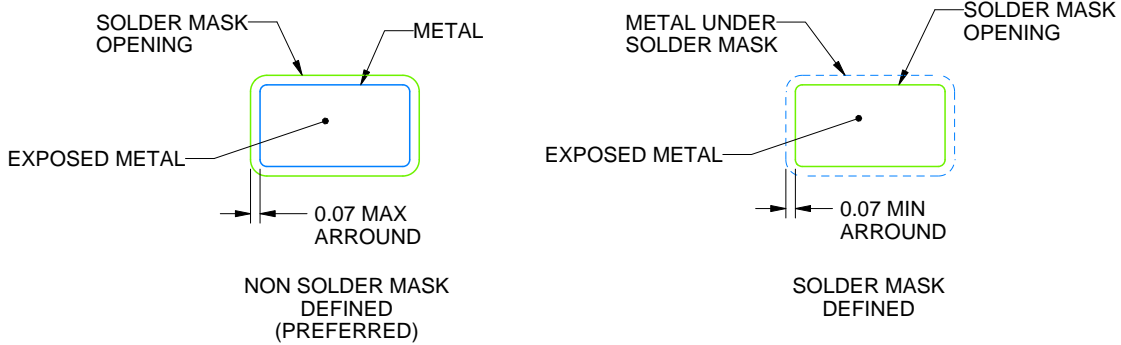
SOLDER MASK DETAILS

4214840/D   09/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

![Texas Instruments logo]
TEXAS INSTRUMENTS

PKG
℄

6X (1.1)

1

6X (0.6)

6

2

SYMM
℄

5

2X(0.95)

3

4

(R0.05) TYP

(2.6)
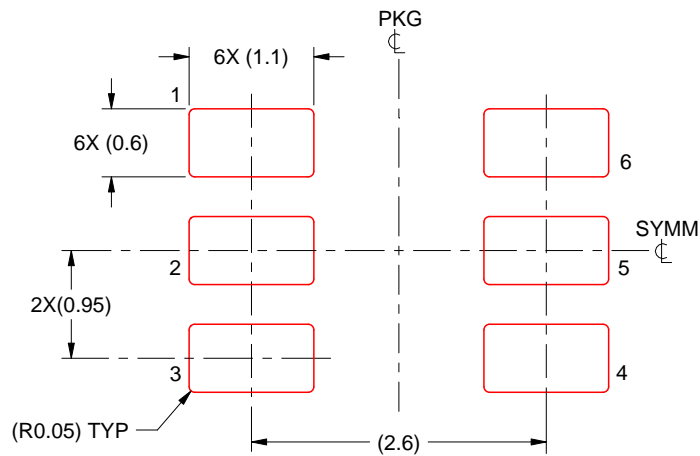
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/D   09/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
design recommendations.
9. Board assembly site may have different recommendations for stencil design.

TEXAS
INSTRUMENTS

D (R−PDSO−G16)   PLASTIC SMALL OUTLINE

$\frac{0.394\ (10,00)}{0.386\ (9,80)}$ /C\

16   9

$\frac{0.244\ (6,20)}{0.228\ (5,80)}$

$\frac{0.157\ (4,00)}{0.150\ (3,80)}$ /D\

1   8

Pin 1
Index Area

0.050 (1,27) $\frac{0.020\ (0,51)}{0.012\ (0,31)}$

⊕ 0.010 (0,25) Ⓜ

0.069 (1,75) Max

$\frac{0.010\ (0,25)}{0.004\ (0,10)}$

$\frac{0.010\ (0,25)}{0.005\ (0,13)}$

◁ 0.004 (0,10)

Gauge Plane

Seating Plane

0.010 (0,25)   0°−8°

$\frac{0.050\ (1,27)}{0.016\ (0,40)}$
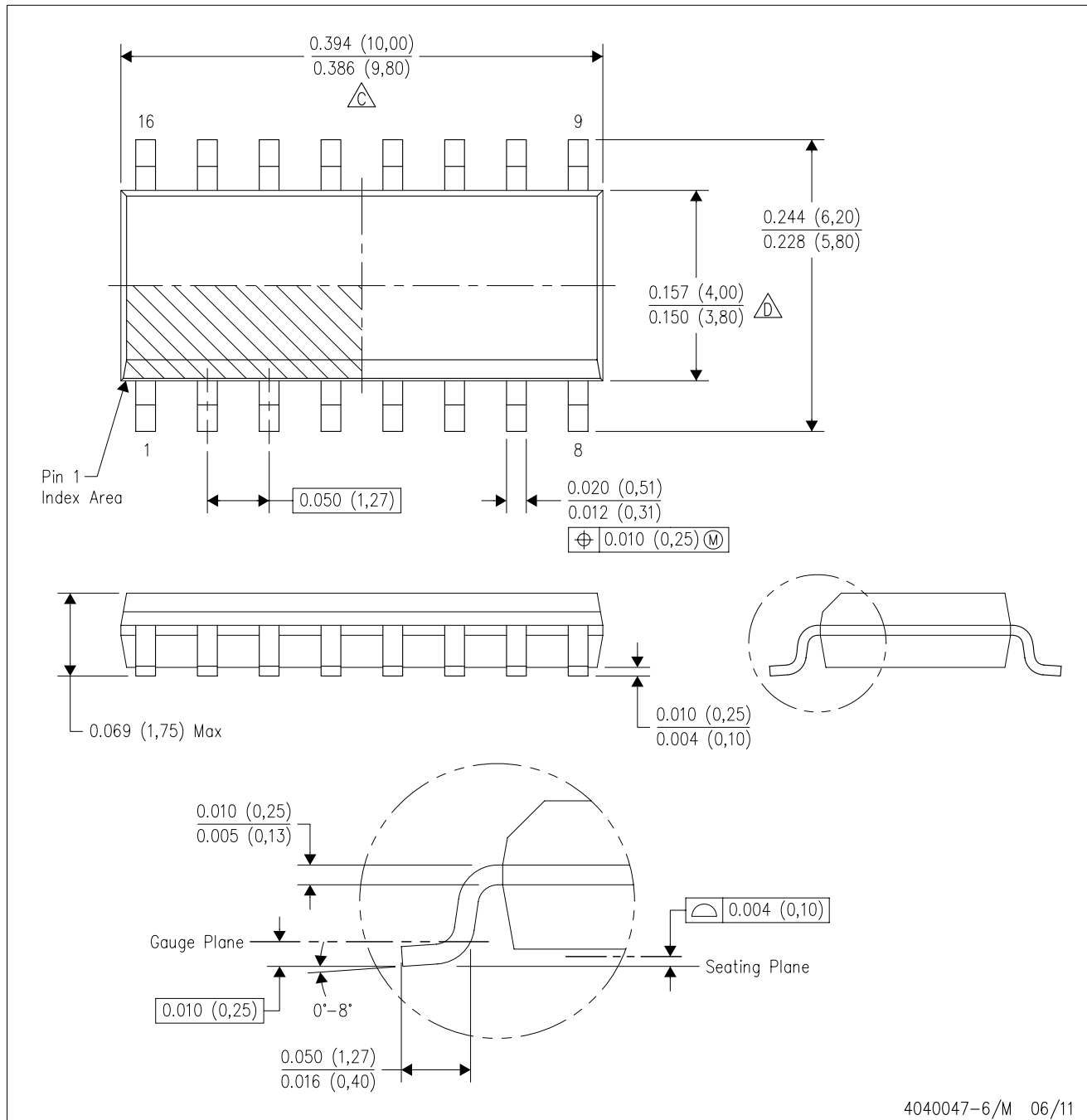
4040047−6/M   06/11

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
      /C\   Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
             not exceed 0.006 (0,15) each side.
      /D\   Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
         E.   Reference JEDEC MS−012 variation AC.
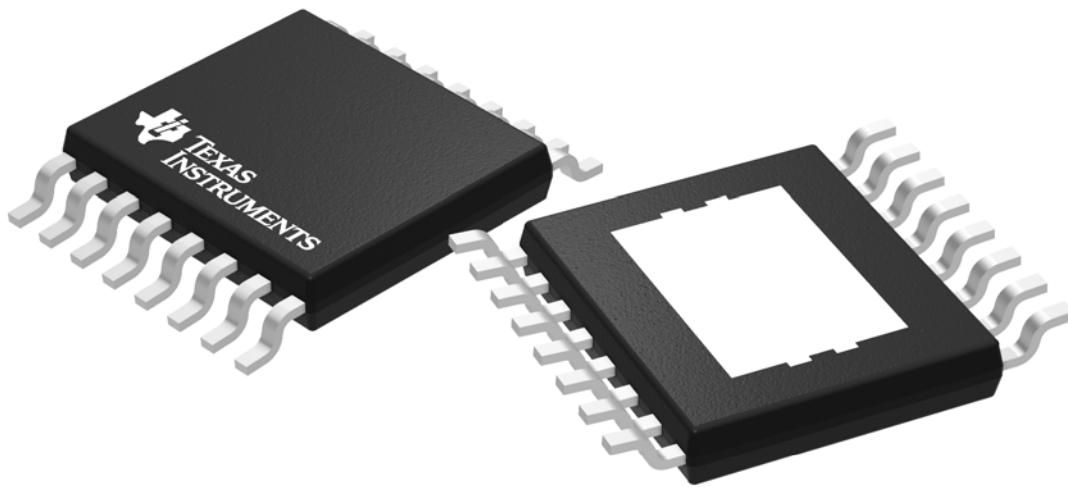
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Instruments
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PWP 16

PowerPAD™ TSSOP - 1.2 mm max height

Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4073225-3/J

Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4224775/A

5.05 / 4.75 TYP

A

PIN 1 ID AREA

1

3.1 / 2.9 NOTE 3

5

B   3.1 / 2.9 NOTE 4

8X 0.5

10

2X 2

6

10X 0.27 / 0.17

⊕ 0.08 Ⓜ C A B

C

SEATING PLANE

◠ 0.1 C

1.1 MAX

0.23 / 0.13 TYP

SEE DETAIL A

EXPOSED THERMAL PAD

4   5

1.89 / 1.69

1   8

1.83 / 1.63

0.25

GAGE PLANE

0° - 8°

0.7 / 0.4

0.15 / 0.05

DETAIL A
TYPICAL

4218842/A   01/2019

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA-T.

TEXAS INSTRUMENTS

(2.2)
NOTE 9

(1.83)
SOLDER MASK
OPENING

SOLDER MASK
DEFINED PAD

SEE DETAILS

10X (0.3)

10X (1.45)

1

(1.3)
TYP

(1.89)
SOLDER MASK
OPENING

(3.1)
NOTE 9

SYMM
₵

8X (0.5)

5

(R0.05) TYP

10

6

(Ø 0.2) TYP
VIA

SYMM
₵

METAL COVERED
BY SOLDER MASK

(1.3) TYP

(4.4)
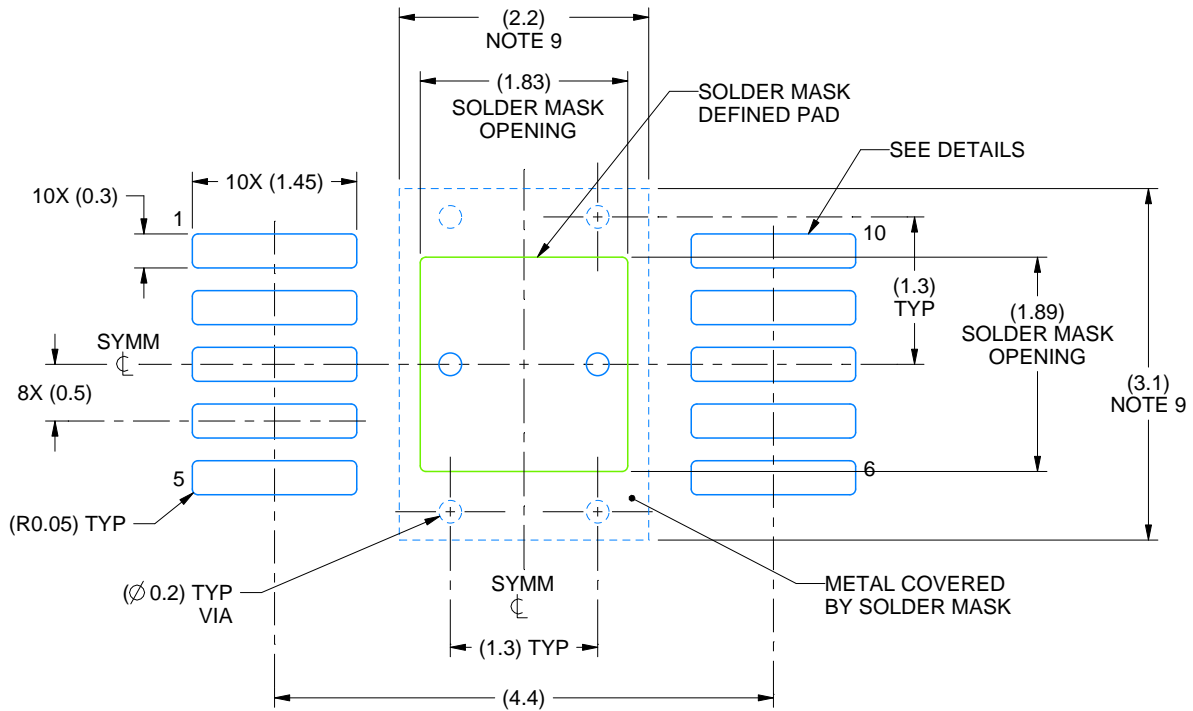
LAND PATTERN EXAMPLE
SCALE:15X

SOLDER MASK
OPENING

METAL

0.05 MAX
ALL AROUND

NON SOLDER MASK
DEFINED

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED
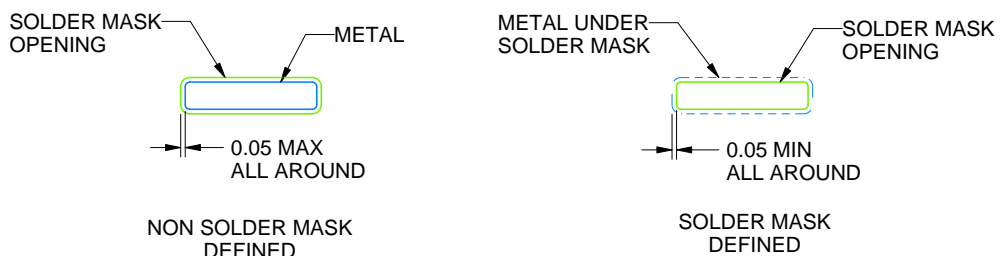
SOLDER MASK DETAILS

4218842/A   01/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.
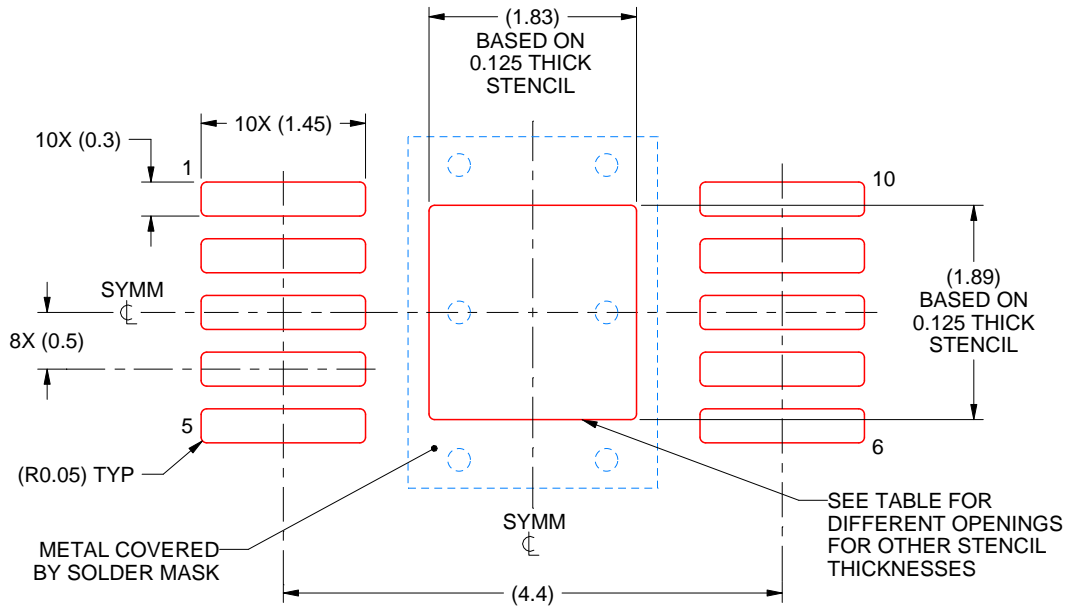
SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	2.05 X 2.11
0.125	1.83 X 1.89 (SHOWN)
0.150	1.67 X 1.73
0.175	1.55 X 1.60

4218842/A 01/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

TEXAS INSTRUMENTS

DGN 8

3 x 3, 0.65 mm pitch

This image is a representation of the package family, actual package may vary.
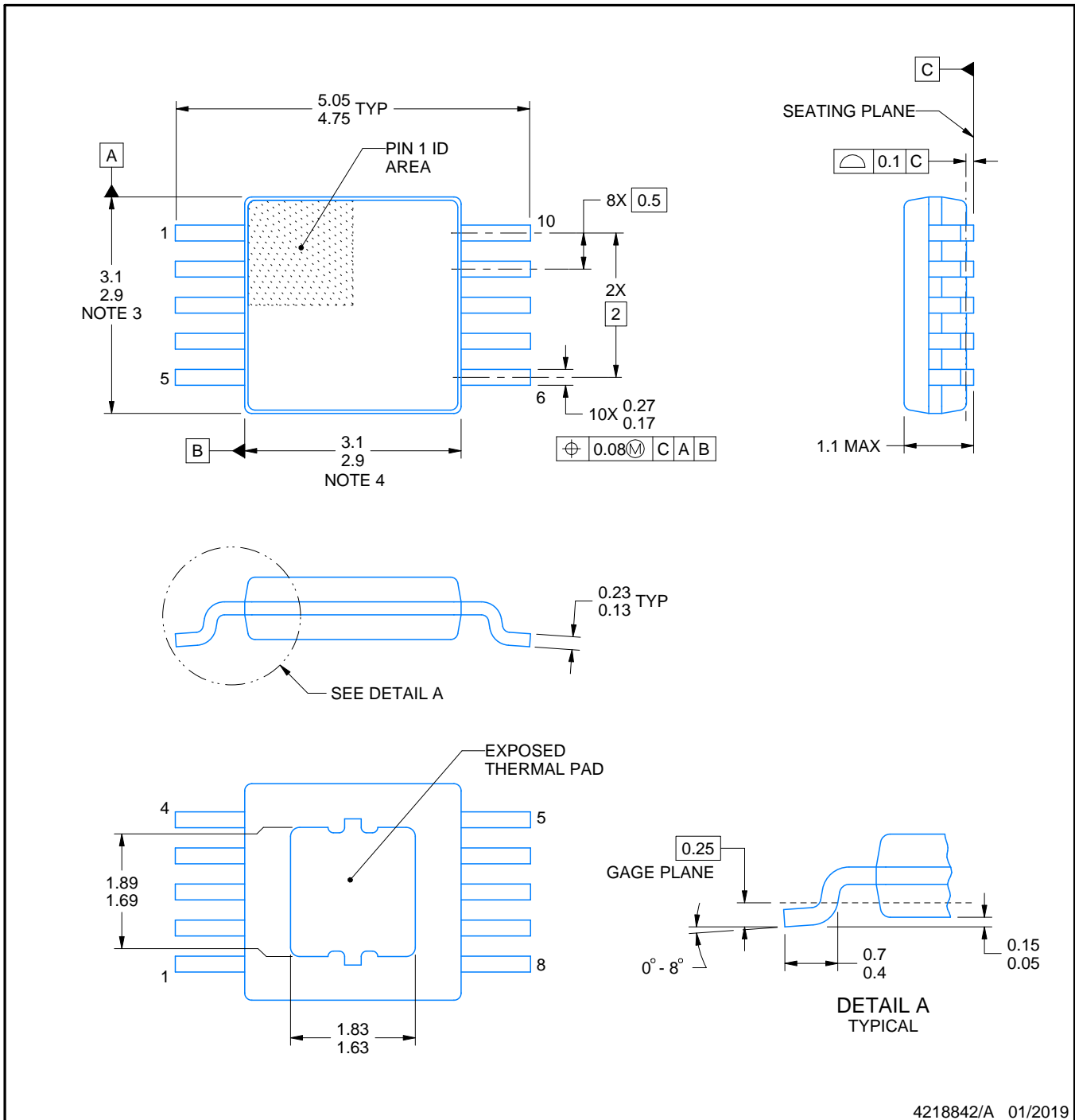Refer to the product data sheet for package details.

4225482/A

TEXAS
INSTRUMENTS

A

5.05
4.75 TYP

PIN 1 INDEX AREA

C

0.1 C

SEATING PLANE

1

8

6X 0.65

3.1
2.9
NOTE 3

2X
1.95

4

5

8X 0.38
0.25

B

3.1
2.9
NOTE 4

0.13 Ⓜ C A B

SEE DETAIL A

0.23
0.13

EXPOSED THERMAL PAD

4

5

1.89
1.63

9

8

1

0.25
GAGE PLANE

1.1 MAX

0°-8°

0.7
0.4

0.15
0.05

DETAIL A
TYPICAL

1.57
1.28

4225481/A   11/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

TEXAS INSTRUMENTS

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

METAL COVERED
BY SOLDER MASK

SOLDER MASK
DEFINED PAD

(R0.05) TYP

8X (1.4)

8X (0.45)

(Ø 0.2) TYP
VIA

6X (0.65)

(2)
NOTE 9

(1.57)

SYMM

SYMM

(3)
NOTE 9

(1.89)

(1.22)

(0.55)

(4.4)

SEE DETAILS

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4225481/A   11/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

TEXAS
INSTRUMENTS

(1.57)
BASED ON
0.125 THICK
STENCIL

SYMM
₵

8X (1.4)

8X (0.45) 1

(R0.05) TYP

8

6X (0.65)

SYMM
₵

(1.89)
BASED ON
0.125 THICK
STENCIL

4

5

METAL COVERED
BY SOLDER MASK

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES

(4.4)

SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

4225481/A   11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

![Texas Instruments logo] TEXAS INSTRUMENTS

DBV0005A

4214839/H   09/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

PKG
℄

5X (1.1)

1

5X (0.6)

5

SYMM
℄

2

(1.9)

2X (0.95)

3

4

(R0.05) TYP

(2.6)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED
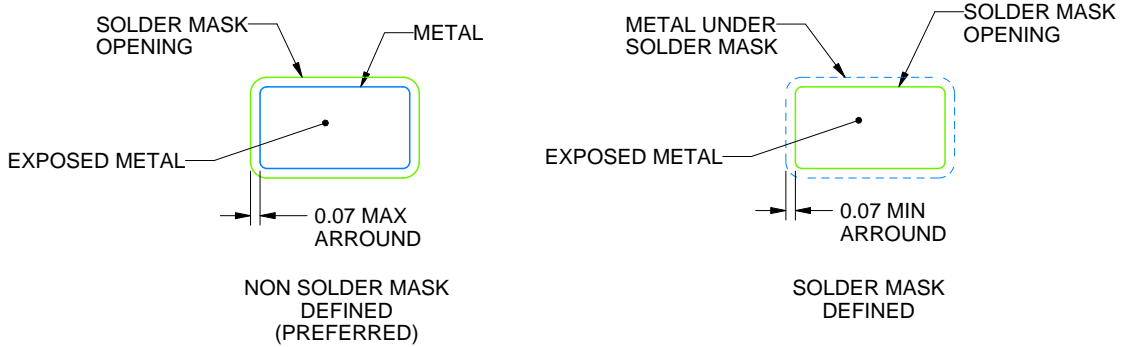
SOLDER MASK DETAILS
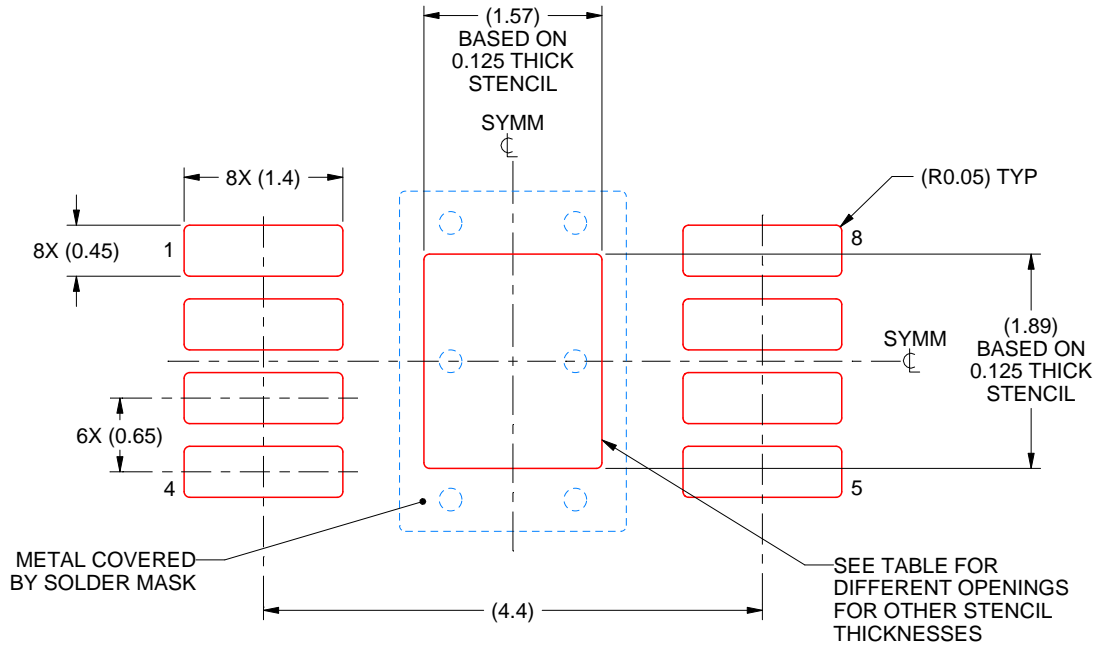
4214839/H   09/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

TEXAS
INSTRUMENTS

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/H   09/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R−PDSO−G14)   PLASTIC SMALL OUTLINE

0.344 (8,75)
0.337 (8,55)
⌖C

14   8

0.244 (6,20)
0.228 (5,80)

0.157 (4,00)
0.150 (3,80)   ⌖D

Pin 1
Index Area

1   7

0.050 (1,27)   0.020 (0,51)
                    0.012 (0,31)
                    ⊕ 0.010 (0,25) Ⓜ

0.069 (1,75) Max

0.010 (0,25)
0.004 (0,10)

0.010 (0,25)
0.005 (0,13)

Gauge Plane

                                    0.004 (0,10)

0.010 (0,25)   0°−8°   Seating Plane

0.050 (1,27)
0.016 (0,40)

4040047−5/M   06/11

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
        ⟋C⟍ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
              not exceed 0.006 (0,15) each side.
        ⟋D⟍ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
         E.   Reference JEDEC MS−012 variation AB.

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INSTRUMENTS**
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D (R−PDSO−G14)   PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

Stencil Openings
(Note D)

12x1,27

14x0,55

14x1,50

12x1,27

5,40

5,40

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

0,60

1,55

0.07

All Around

Example
Solder Mask Opening
(See Note E)

4211283−3/E 08/12

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Publication IPC−7351 is recommended for alternate designs.
         D.   Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
              contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
         E.   Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

**TEXAS
INSTRUMENTS**
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PW (R−PDSO−G14)   PLASTIC SMALL OUTLINE

0,65   0,30 / 0,19   ⊕ | 0,10 Ⓜ

14   8

D   4,50 / 4,30   6,60 / 6,20

1   7

5,10 / 4,90

C

0,15 NOM

Gage Plane

0°−8°   0,25

0,75 / 0,50

1,20 MAX   0,15 / 0,05

Seating Plane   0,10

4040064−3/G   02/11

NOTES: A.   All linear dimensions are in millimeters.   Dimensioning and tolerancing per ASME Y14.5M−1994.
          B.   This drawing is subject to change without notice.
          C.   Body length does not include mold flash, protrusions, or gate burrs.   Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
          D.   Body width does not include interlead flash.   Interlead flash shall not exceed 0,25 each side.
          E.   Falls within JEDEC MO−153

TEXAS INSTRUMENTS

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This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4224995/A

PWP (R−PDSO−G14)   PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL PAD

SIZE AND SHAPE
SHOWN ON
SEPARATE SHEET

0,65

14   8

0,30
0,19   ⊕ | 0,10 Ⓜ

4,50
4,30

6,60
6,20

1   7

5,10
4,90

0,15 NOM

Seating Plane

Gauge Plane

0,25

0°−8°

0,75
0,50

1,20 MAX

0,15
0,05

Seating Plane

⌓ | 0,10

4073225−2/I 05/11

NOTES: A.   All linear dimensions are in millimeters.
            B.   This drawing is subject to change without notice.
            C.   Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
            D.   This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad
                 Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding
                 recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
            E.   See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
            E.   Falls within JEDEC MO−153

PowerPAD is a trademark of Texas Instruments.

**TEXAS
INSTRUMENTS**

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PWP (R—PDSO—G14)   PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

14   8

$\dfrac{2,46}{1,65}$

Exposed Thermal Pad

1   7

$\dfrac{2,31}{1,35}$

Top View

Exposed Thermal Pad Dimensions

4206332—2/AO 01/16

NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

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PWP (R−PDSO−G14)   PowerPAD™ PLASTIC SMALL OUTLINE

Example Board Layout
Via pattern and copper pad size
may vary depending on layout constraints

Stencil Openings
Based on a stencil thickness
of .127mm (.005inch).
Reference table below for other
solder stencil thicknesses

Increasing copper area will
enhance thermal performance
(See Note D)

Solder Mask
Over Copper

4x1,5   12x0,65

2,46 3,4 5,6
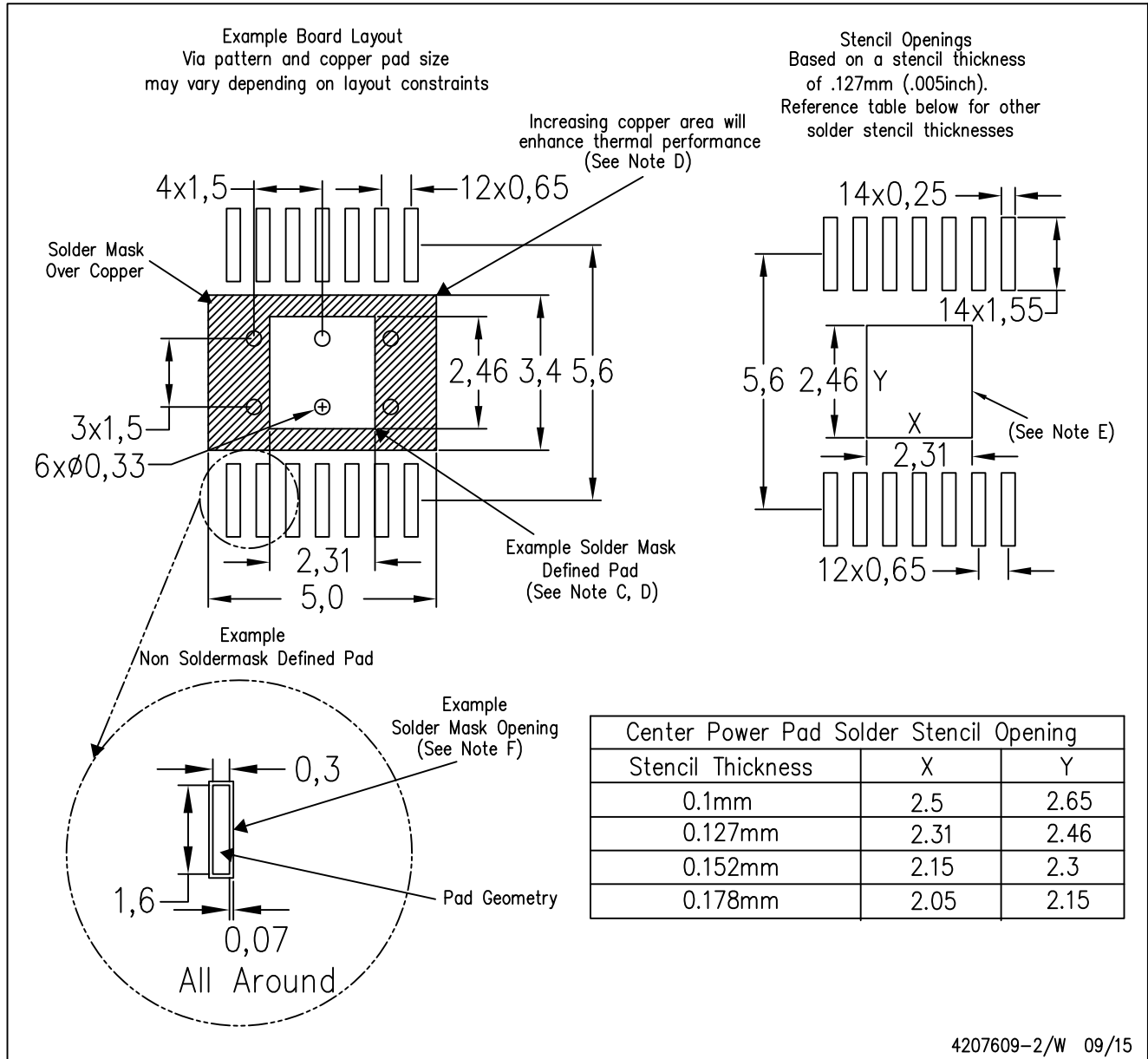
3x1,5

6x∅0,33

2,31

5,0

Example Solder Mask
Defined Pad
(See Note C, D)

14x0,25

14x1,55

5,6 2,46   Y

X

2,31

(See Note E)

12x0,65

Example
Non Soldermask Defined Pad

Example
Solder Mask Opening
(See Note F)

0,3

1,6

0,07
All Around

Pad Geometry

Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.5	2.65
0.127mm	2.31	2.46
0.152mm	2.15	2.3
0.178mm	2.05	2.15

4207609−2/W 09/15

NOTES: A.   All linear dimensions are in millimeters.
B.   This drawing is subject to change without notice.
C.   Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D.   This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad
Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets
for specific thermal information, via requirements, and recommended board layout. These documents are available at
www.ti.com <http://www.ti.com>. Publication IPC−7351 is recommended for alternate designs.
E.   Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric
metal load solder paste. Refer to IPC−7525 for other stencil recommendations.
F.   Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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PWP (R—PDSO—G14)   PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL PAD
SIZE AND SHAPE
SHOWN ON
SEPARATE SHEET

0,65

0,30
0,19

⊕ 0,10 Ⓜ

14   8

4,50
4,30

6,60
6,20

1   7

5,10
4,90

0,15 NOM

Seating Plane

Gauge Plane

0,25

0°–8°

0,75
0,50

1,20 MAX

0,15
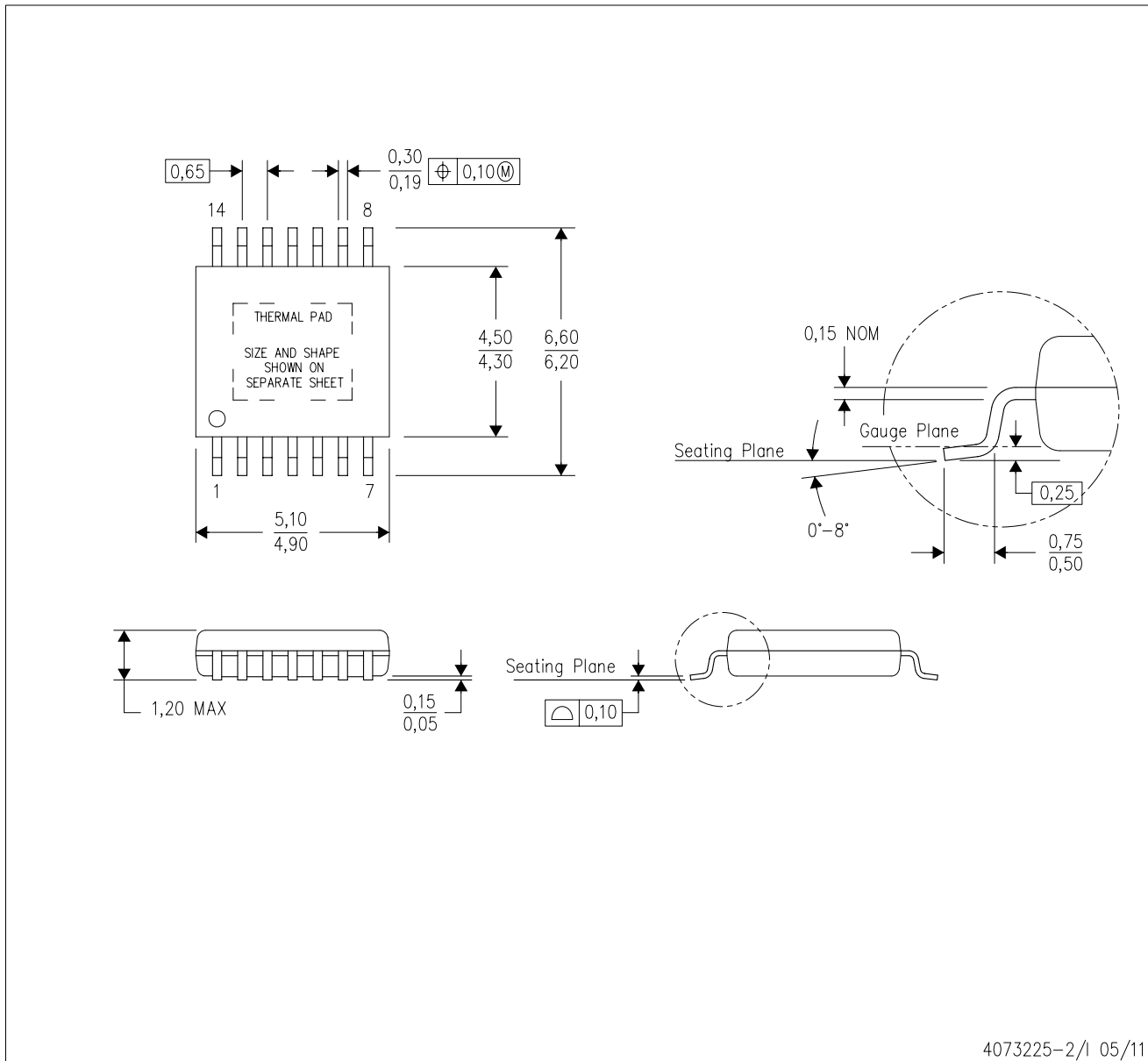0,05

Seating Plane

⌒ 0,10

4073225–2/I 05/11

NOTES: A.   All linear dimensions are in millimeters.
          B.   This drawing is subject to change without notice.
          C.   Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
          D.   This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad
               Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding
               recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
          E.   See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
          E.   Falls within JEDEC MO–153

PowerPAD is a trademark of Texas Instruments.

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PWP (R−PDSO−G14)   PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

Top View

Exposed Thermal Pad Dimensions

4206332−44/AO 01/16

NOTE: A. All linear dimensions are in millimeters
         B. Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments

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PWP (R−PDSO−G14)　　　　PowerPAD™ PLASTIC SMALL OUTLINE

Example Board Layout
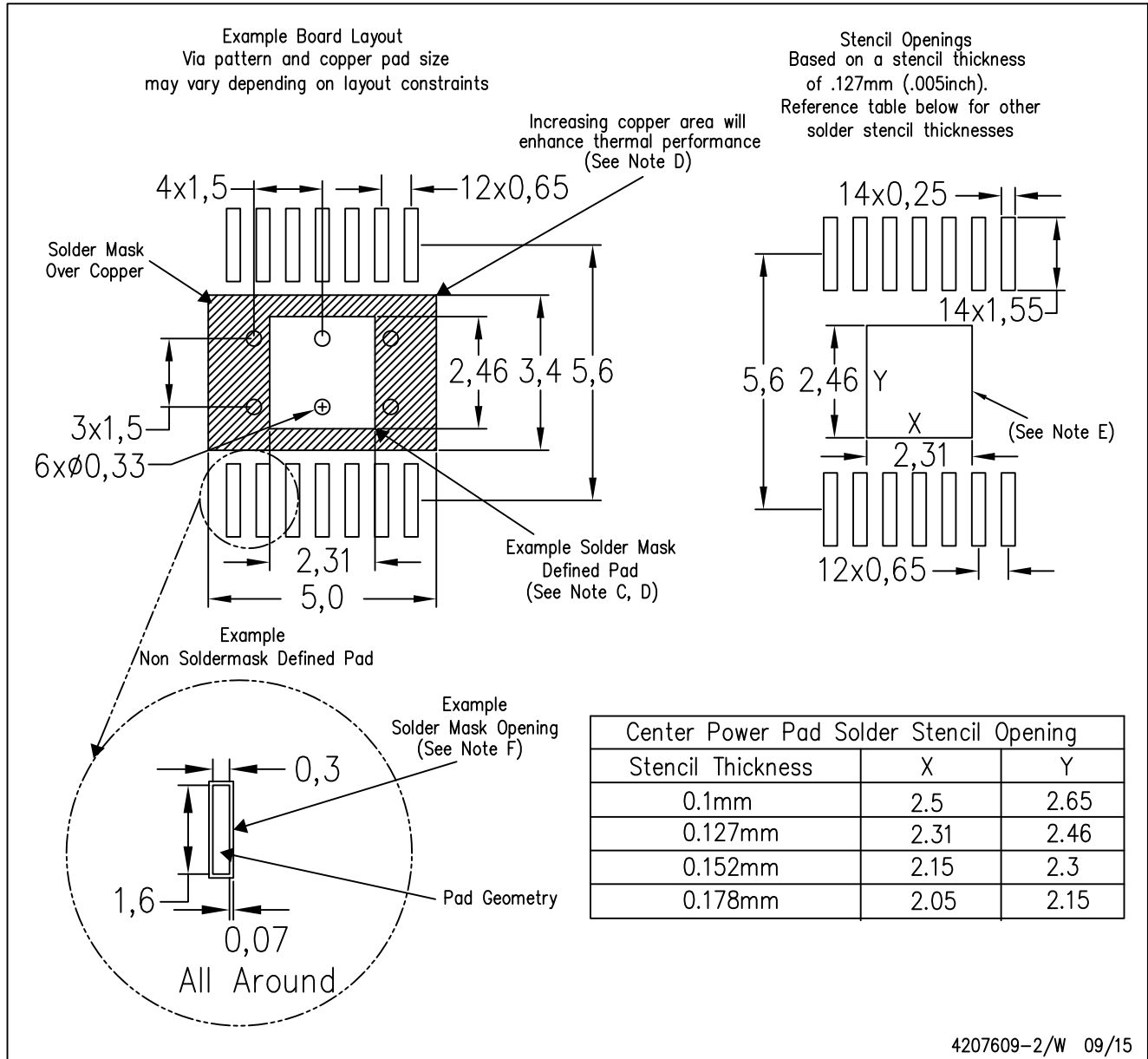Via pattern and copper pad size
may vary depending on layout constraints

Stencil Openings
Based on a stencil thickness
of .127mm (.005inch).
Reference table below for other
solder stencil thicknesses

Increasing copper area will
enhance thermal performance
(See Note D)

Solder Mask
Over Copper

4x1,5　　　　12x0,65

14x0,25

2,46 3,4 5,6

5,6 2,46　Y

X

2,31

(See Note E)

3x1,5

6x∅0,33

14x1,55

12x0,65

2,31

5,0

Example Solder Mask
Defined Pad
(See Note C, D)

Example
Non Soldermask Defined Pad

Example
Solder Mask Opening
(See Note F)

0,3

1,6

0,07

All Around

Pad Geometry

Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.5	2.65
0.127mm	2.31	2.46
0.152mm	2.15	2.3
0.178mm	2.05	2.15

4207609−2/W　09/15

NOTES:　A.　All linear dimensions are in millimeters.
　　　　　B.　This drawing is subject to change without notice.
　　　　　C.　Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
　　　　　D.　This package is designed to be soldered to a thermal pad on the board.　Refer to Technical Brief, PowerPad
　　　　　　　Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets
　　　　　　　for specific thermal information, via requirements, and recommended board layout.　These documents are available at
　　　　　　　www.ti.com <http://www.ti.com>.　Publication IPC−7351 is recommended for alternate designs.
　　　　　E.　Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.　Customers should
　　　　　　　contact their board assembly site for stencil design recommendations.　Example stencil design based on a 50% volumetric
　　　　　　　metal load solder paste.　Refer to IPC−7525 for other stencil recommendations.
　　　　　F.　Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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.228-.244 TYP
[5.80-6.19]

A

PIN 1 ID AREA

1

8

6X .050
[1.27]

2X

.150
[3.81]

.189-.197
[4.81-5.00]
NOTE 3

4

5

8X .012-.020
[0.31-0.51]

B

.150-.157
[3.81-3.98]
NOTE 4

⊕ .010 [0.25]Ⓜ C A B

C

SEATING PLANE

◠ .004 [0.1] C

4X (0°-15°)

.069 MAX
[1.75]

.005-.010 TYP
[0.13-0.25]

4X (0°-15°)

SEE DETAIL A

.010
[0.25]

0° - 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

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8X (.061)
[1.55]

SYMM
₵

SEE
DETAILS

1

8

8X (.024)
[0.6]

SYMM
₵

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

.0028 MIN
[0.07]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

8X (.061)
[1.55]

SYMM

1

8X (.024)
[0.6]

SYMM

8

(R.002) TYP
[0.05]

6X (.050)
[1.27]

4

5

(.213)
[5.4]

SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C   02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R−PDIP−T8)   PLASTIC DUAL−IN−LINE PACKAGE

0.400 (10,16)
0.355 (9,02)

8   5

0.260 (6,60)
0.240 (6,10)

1   4

0.070 (1,78)
0.045 (1,14)

0.045 (1,14)
0.030 (0,76)

0.020 (0,51) MIN

0.325 (8,26)
0.300 (7,62)

0.015 (0,38)

0.200 (5,08) MAX

Gauge Plane

Seating Plane

0.010 (0,25) NOM

0.125 (3,18) MIN

0.100 (2,54)

0.430 (10,92)
MAX

0.021 (0,53)
0.015 (0,38)

⊕ | 0.010 (0,25) Ⓜ

4040082/E   04/2010

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
         C.   Falls within JEDEC MS−001 variation BA.

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N (R−PDIP−T**)
16 PINS SHOWN

PLASTIC DUAL−IN−LINE PACKAGE

DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS−001 VARIATION	AA	BB	AC	AD

A

16   9

0.260 (6,60)
0.240 (6,10)

1   8

0.070 (1,78)
0.045 (1,14)

0.045 (1,14)
0.030 (0,76)

0.020 (0,51) MIN

0.325 (8,26)
0.300 (7,62)

0.015 (0,38)

Gauge Plane

0.200 (5,08) MAX

Seating Plane

0.125 (3,18) MIN

0.010 (0,25) NOM

0.100 (2,54)

0.021 (0,53)
0.015 (0,38)

⊕ 0.010 (0,25) Ⓜ

0.430 (10,92) MAX

14/18 Pin Only
20 Pin vendor option

4040049/E 12/2002

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
         C.   Falls within JEDEC MS−001, except 18 and 20 pin minimum body length (Dim A).
         D.   The 20 pin end lead shoulder width is a vendor option, either half or full width.

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